

# Silicon Power Transistors

The MJ21193 and MJ21194 utilize Perforated Emitter technology and are specifically designed for high power audio output, disk head positioners and linear applications.

- Total Harmonic Distortion Characterized
- High DC Current Gain –  
 $h_{FE} = 25 \text{ Min @ } I_C = 8 \text{ Adc}$
- Excellent Gain Linearity
- High SOA: 2.5 A, 80 V, 1 Second

## MAXIMUM RATINGS

Rating	Sym- bol	Value	Unit
Collector–Emitter Voltage	$V_{CEO}$	250	Vdc
Collector–Base Voltage	$V_{CBO}$	400	Vdc
Emitter–Base Voltage	$V_{EBO}$	5	Vdc
Collector–Emitter Voltage – 1.5 V	$V_{CEX}$	400	Vdc
Collector Current — Continuous Peak <sup>(1)</sup>	$I_C$	16 30	Adc
Base Current — Continuous	$I_B$	5	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate Above $25^\circ\text{C}$	$P_D$	250 1.43	Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J$ , $T_{stg}$	–65 to +200	$^\circ\text{C}$

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	0.7	$^\circ\text{C/W}$

## ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typical	Max	Unit
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## OFF CHARACTERISTICS

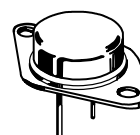
Collector–Emitter Sustaining Voltage ( $I_C = 100 \text{ mAdc}$ , $I_B = 0$ )	$V_{CEO(sus)}$	250	—	—	Vdc
Collector Cutoff Current ( $V_{CE} = 200 \text{ Vdc}$ , $I_B = 0$ )	$I_{CEO}$	—	—	100	$\mu\text{Adc}$

(1) Pulse Test: Pulse Width = 5  $\mu\text{s}$ , Duty Cycle  $\leq 10\%$ . (continued)

**PNP**  
**MJ21193\***  
**NPN**  
**MJ21194\***

\*ON Semiconductor Preferred Device

**16 AMPERE  
COMPLEMENTARY  
SILICON POWER  
TRANSISTORS  
250 VOLTS  
250 WATTS**



**CASE 1-07  
TO-204AA  
(TO-3)**

Preferred devices are ON Semiconductor recommended choices for future use and best overall value.

# MJ21193 MJ21194

## ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typical	Max	Unit
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### OFF CHARACTERISTICS

Emitter Cutoff Current ( $V_{CE} = 5\text{ Vdc}$ , $I_C = 0$ )	$I_{EBO}$	—	—	100	$\mu\text{Adc}$
Collector Cutoff Current ( $V_{CE} = 250\text{ Vdc}$ , $V_{BE(off)} = 1.5\text{ Vdc}$ )	$I_{CEX}$	—	—	100	$\mu\text{Adc}$

### SECOND BREAKDOWN

Second Breakdown Collector Current with Base Forward Biased ( $V_{CE} = 50\text{ Vdc}$ , $t = 1\text{ s}$ (non-repetitive)) ( $V_{CE} = 80\text{ Vdc}$ , $t = 1\text{ s}$ (non-repetitive))	$I_{S/b}$	5 2.5	— —	— —	$\text{Adc}$
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### ON CHARACTERISTICS

DC Current Gain ( $I_C = 8\text{ Adc}$ , $V_{CE} = 5\text{ Vdc}$ ) ( $I_C = 16\text{ Adc}$ , $I_B = 5\text{ Adc}$ )	$h_{FE}$	25 8	— —	75	
Base-Emitter On Voltage ( $I_C = 8\text{ Adc}$ , $V_{CE} = 5\text{ Vdc}$ )	$V_{BE(on)}$	—	—	2.2	$\text{Vdc}$
Collector-Emitter Saturation Voltage ( $I_C = 8\text{ Adc}$ , $I_B = 0.8\text{ Adc}$ ) ( $I_C = 16\text{ Adc}$ , $I_B = 3.2\text{ Adc}$ )	$V_{CE(sat)}$	— —	— —	1.4 4	$\text{Vdc}$

### DYNAMIC CHARACTERISTICS

Total Harmonic Distortion at the Output $V_{RMS} = 28.3\text{ V}$ , $f = 1\text{ kHz}$ , $P_{LOAD} = 100\text{ W}_{RMS}$  ed (Matched pair $h_{FE} = 50 @ 5\text{ A}/5\text{ V}$ )	$T_{HD}$	— —	0.8 0.08	— —	%
Current Gain Bandwidth Product ( $I_C = 1\text{ Adc}$ , $V_{CE} = 10\text{ Vdc}$ , $f_{test} = 1\text{ MHz}$ )	$f_T$	4	—	—	$\text{MHz}$
Output Capacitance ( $V_{CB} = 10\text{ Vdc}$ , $I_E = 0$ , $f_{test} = 1\text{ MHz}$ )	$C_{ob}$	—	—	500	$\text{pF}$

(1) Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle  $\leq 2\%$

PNP MJ21193

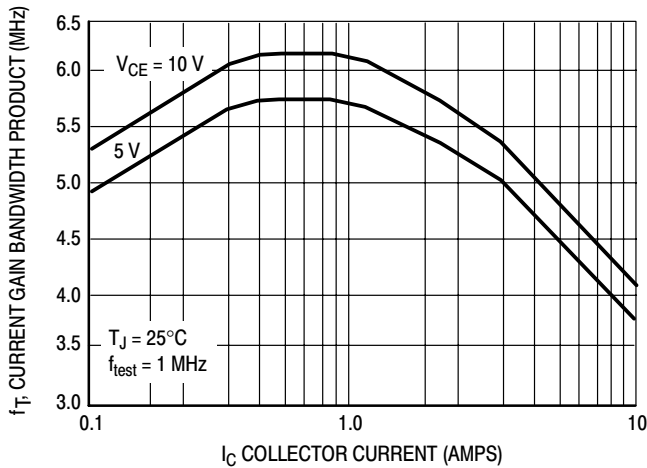


Figure 1. Typical Current Gain Bandwidth Product

NPN MJ21194

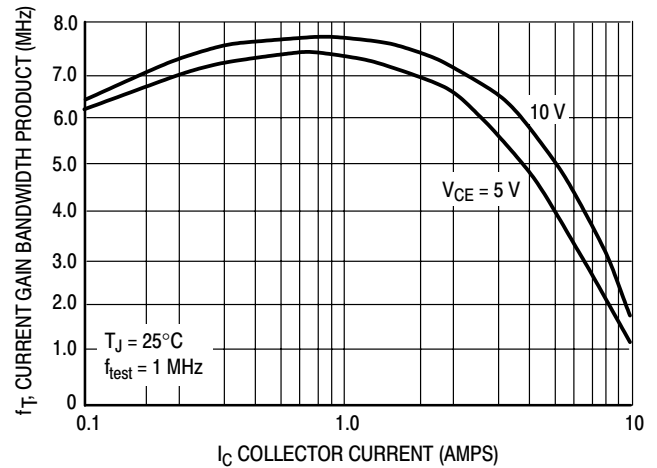


Figure 2. Typical Current Gain Bandwidth Product

TYPICAL CHARACTERISTICS

PNP MJ21193

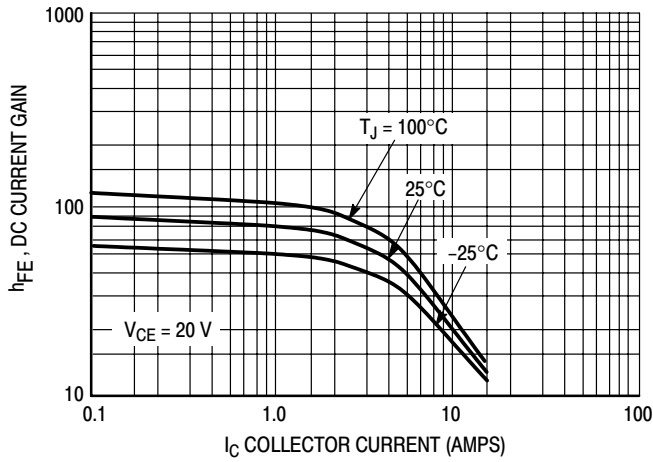


Figure 3. DC Current Gain,  $V_{CE} = 20\text{ V}$

NPN MJ21194

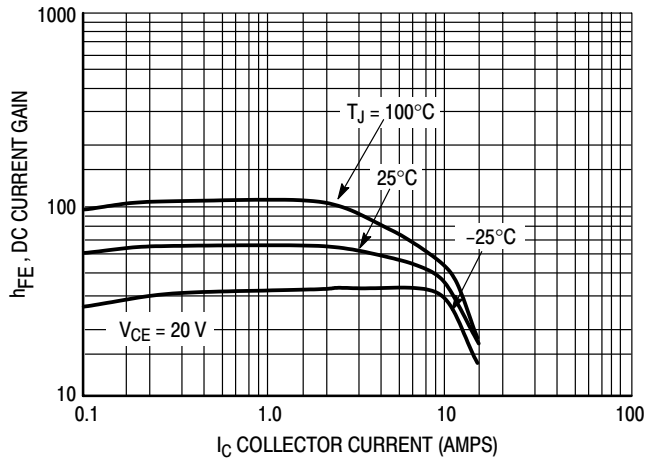


Figure 4. DC Current Gain,  $V_{CE} = 20\text{ V}$

PNP MJ21193

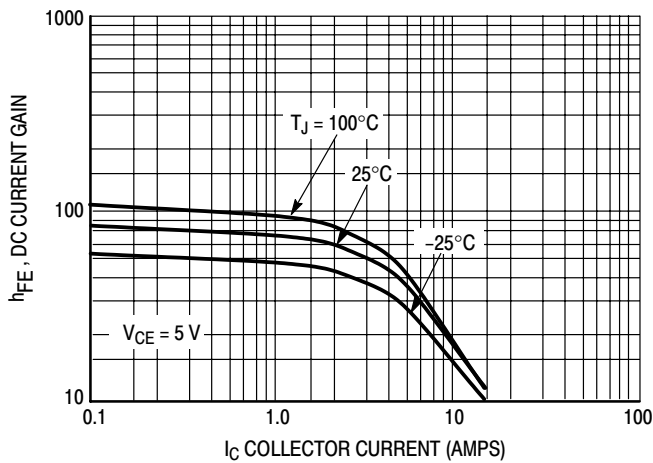


Figure 5. DC Current Gain,  $V_{CE} = 5\text{ V}$

NPN MJ21194

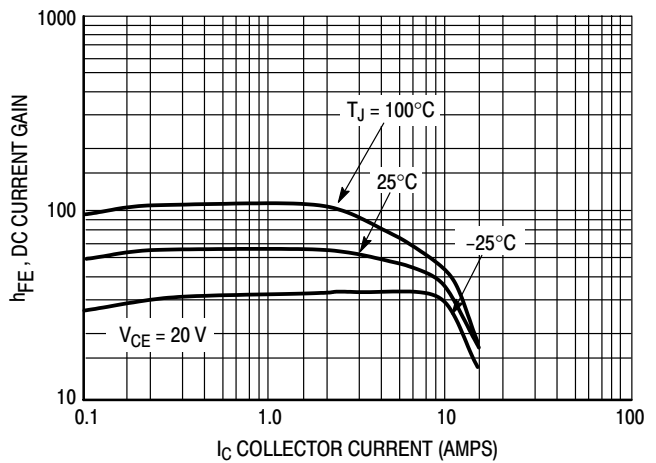


Figure 6. DC Current Gain,  $V_{CE} = 5\text{ V}$

PNP MJ21193

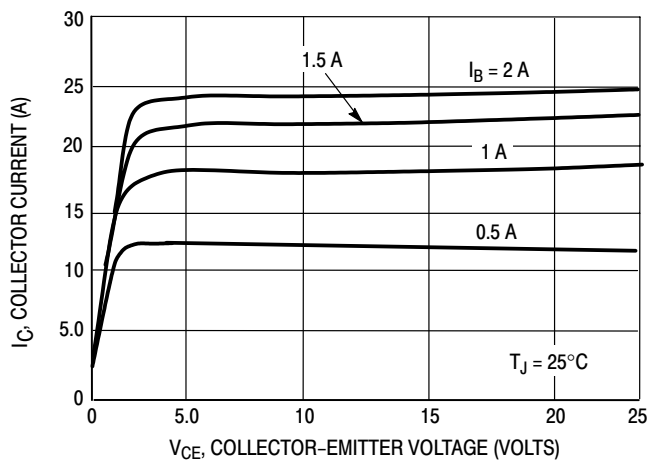


Figure 7. Typical Output Characteristics

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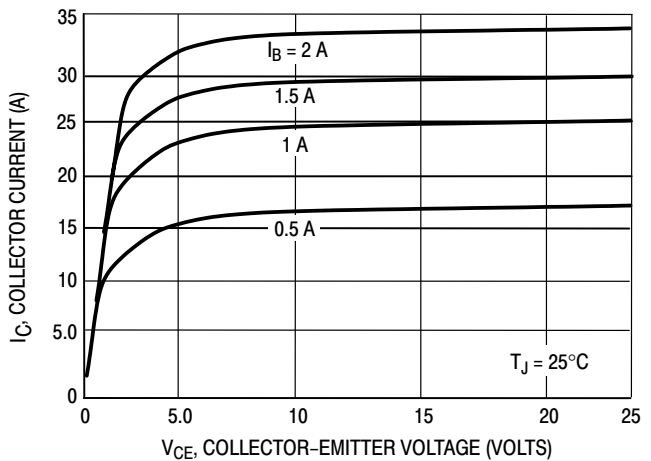


Figure 8. Typical Output Characteristics

TYPICAL CHARACTERISTICS

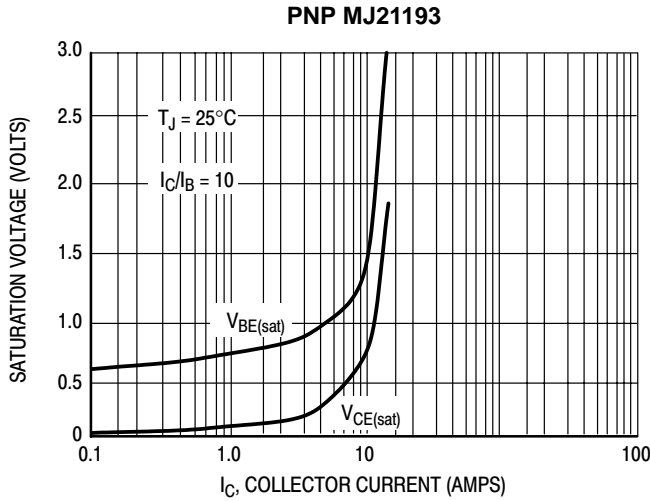


Figure 9. Typical Saturation Voltages

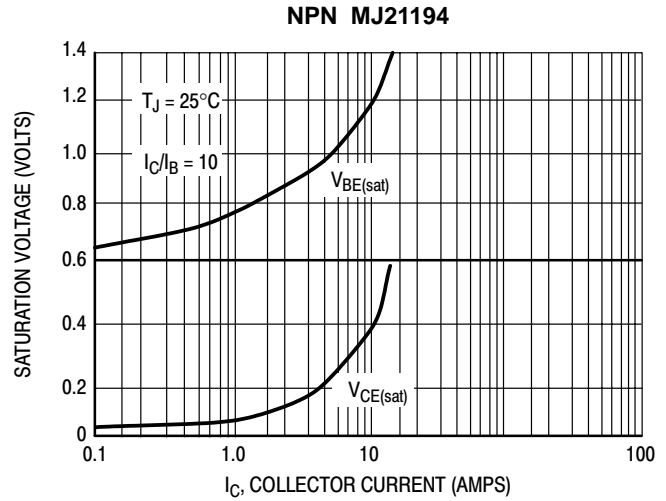


Figure 10. Typical Saturation Voltages

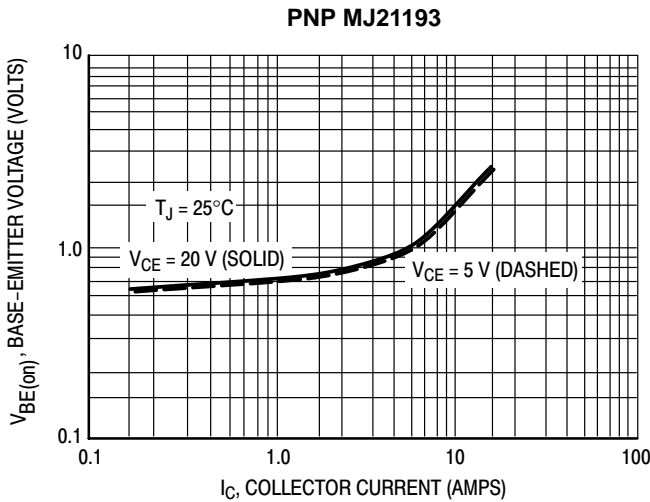


Figure 11. Typical Base-Emitter Voltage

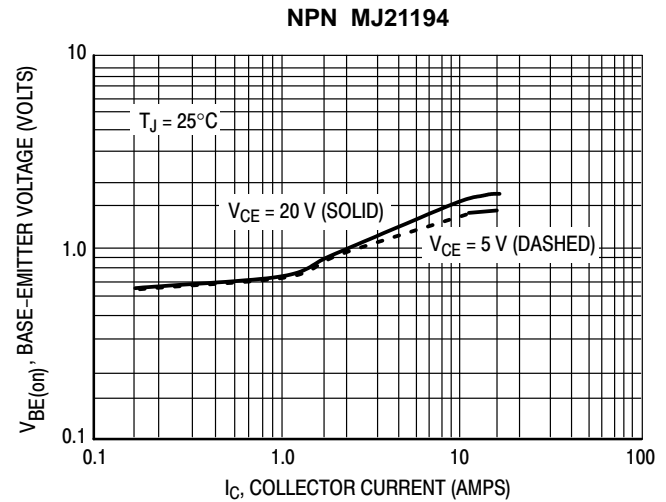


Figure 12. Typical Base-Emitter Voltage

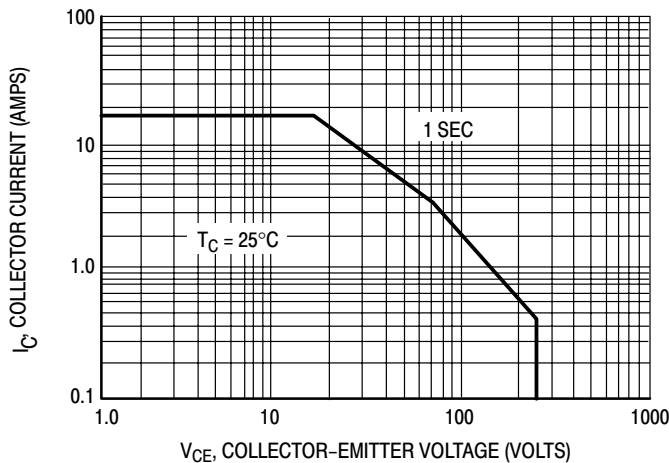


Figure 13. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 13 is based on  $T_{J(pk)} = 200^\circ\text{C}$ ;  $T_C$  is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

## MJ21193 MJ21194

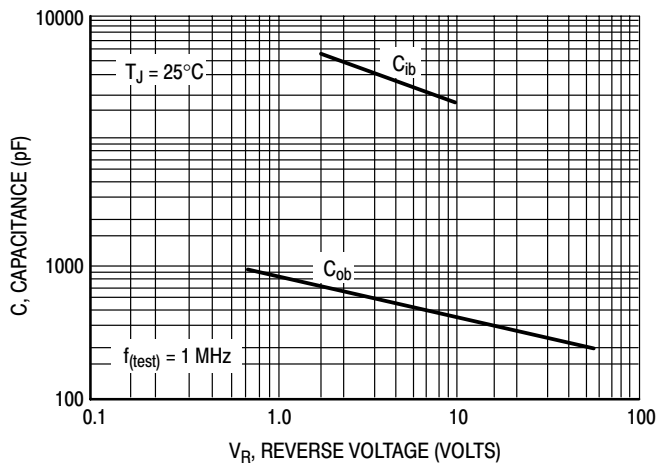


Figure 14. MJ21193 Typical Capacitance

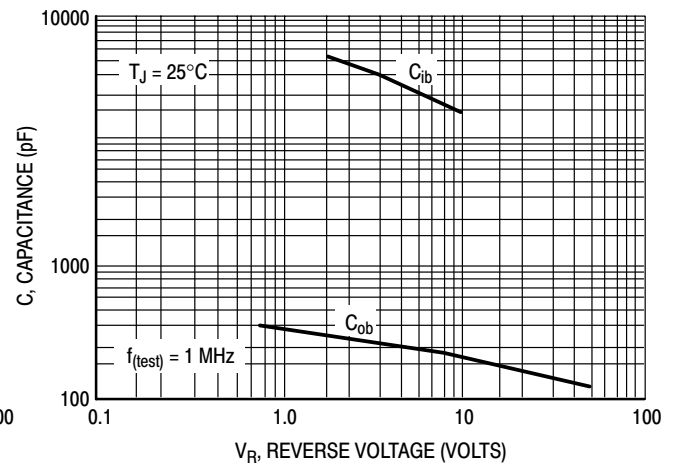


Figure 15. MJ21194 Typical Capacitance

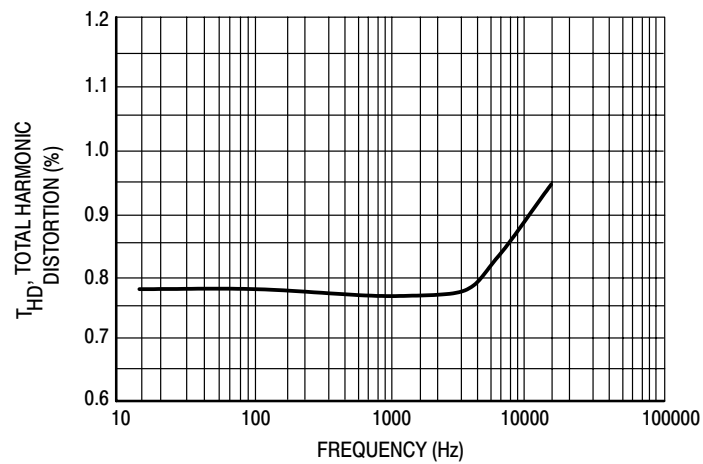


Figure 16. Typical Total Harmonic Distortion

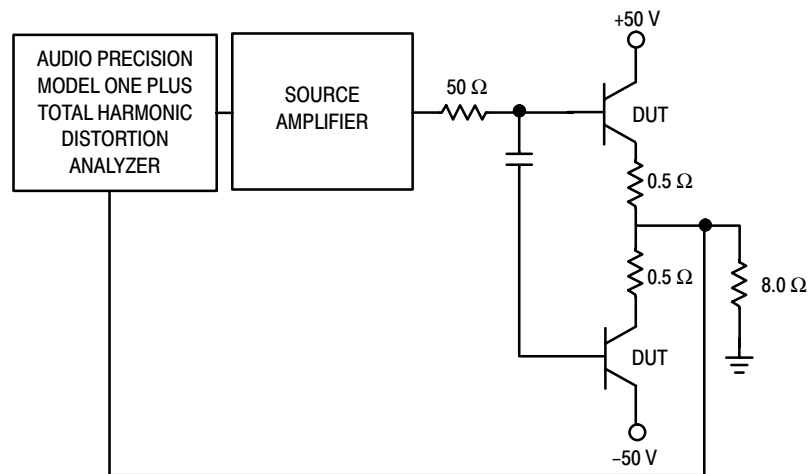


Figure 17. Total Harmonic Distortion Test Circuit



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